

Pb Free Plating Product

FCH10A045/FCH10A06/FCH10A10/FCH10A15/FCH10A20



10.0 Ampere Insulated Dual Common Cathode Schottky Barrier Rectifiers

Features

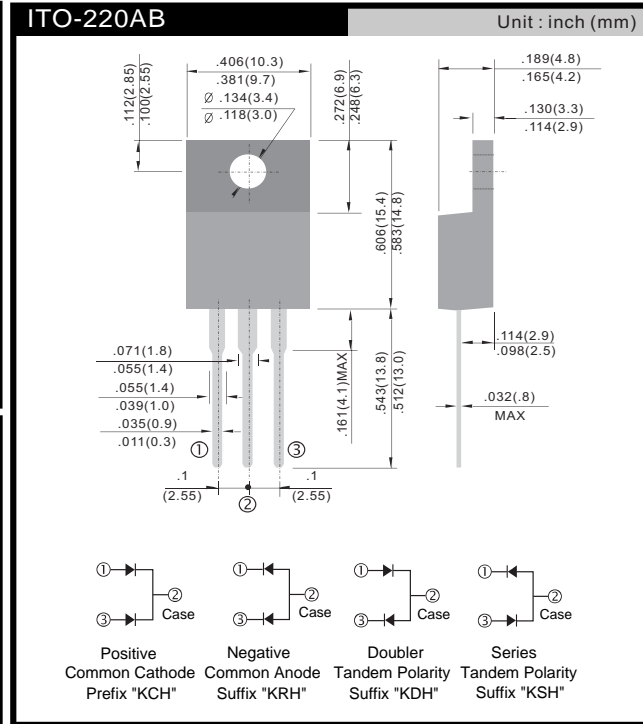
- * Fast switching for high efficiency
- * Low forward voltage drop
- * High current capability
- * Low reverse leakage current
- * High surge current capability

Application

- * Automotive Inverters and Solar Inverters
- * Plating Power Supply, SMPS and UPS
- * Car Audio Amplifiers and Sound Device Systems

Mechanical Data

- * Case: Fully Isolated TO-220FP FullPak Plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Terminals: Solderable per MIL-STD-202 method 208
- * Polarity: As marked on diode body
- * Mounting position: Any
- * Weight: 2.0 gram approxiamtely



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | KCH 10A045 | KCH 10A06 | KCH 10A10 | KCH 10A15 | KCH 10A20 | UNIT |
|--|--------------------|------------------------------|------------------------------|------------------------------|------------------------------|-----------|------|
| Marking code | | KCH10A045 | KCH10A06 | KCH10A10 | KCH10A15 | KCH10A20 | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 45 | 60 | 100 | 150 | 200 | V |
| Maximum RMS voltage | V _{RMS} | 31 | 42 | 70 | 105 | 140 | V |
| Maximum DC blocking voltage | V _{DC} | 45 | 60 | 100 | 150 | 200 | V |
| Maximum average forward rectified current | I _{F(AV)} | 10 | | | | | A |
| Peak repetitive forward current (Rated VR, Square wave, 20KHz) | I _{FRM} | 10 | | | | | A |
| Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} | 120 | | | | | A |
| Peak repetitive reverse surge current (Note 1) | I _{RRM} | 1 | 0.5 | | | | A |
| Maximum instantaneous forward voltage (Note 2) I _F = 5 A, T _J =25°C I _F = 5 A, T _J =125°C I _F = 10 A, T _J =25°C I _F = 10 A, T _J =125°C | V _F | 0.70 0.57 0.80 0.67 | 0.80 0.65 0.90 0.75 | 0.85 0.75 0.95 0.85 | 0.88 0.78 0.98 0.88 | | V |
| Maximum reverse current @ rated VR T _J =25 °C T _J =125 °C | I _R | 0.1 | | | | | mA |
| | | 15 | 10 | 2 | 5 | | |
| Voltage rate of change (Rated V _R) | dV/dt | 10000 | | | | | V/μs |
| Typical thermal resistance | R _{θJC} | 1.5 | | | | | /W |
| Operating junction temperature range | T _J | - 55 to +150 | | | | | |
| Storage temperature range | T _{STG} | - 55 to +150 | | | | | |

Note 1: tp = 2.0 μs, 1.0KHz

Note 2: Pulse test with PW=300μs, 1% duty cycle

RATINGS AND CHARACTERISTICS CURVES

(TA=25°C unless otherwise noted)

FIG. 1- FORWARD CURRENT DERATING CURVE

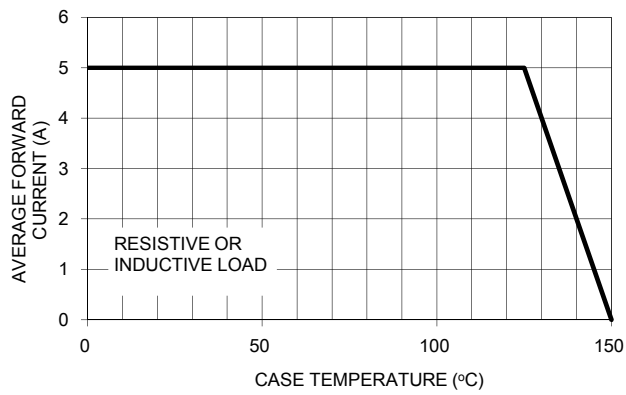


FIG. 2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

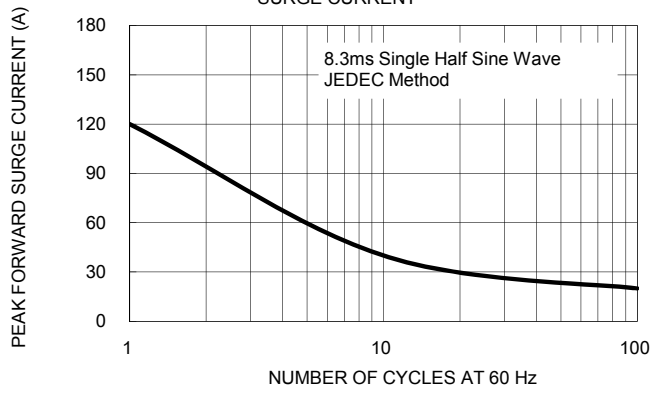


FIG. 3- TYPICAL FORWARD CHARACTERISTICS

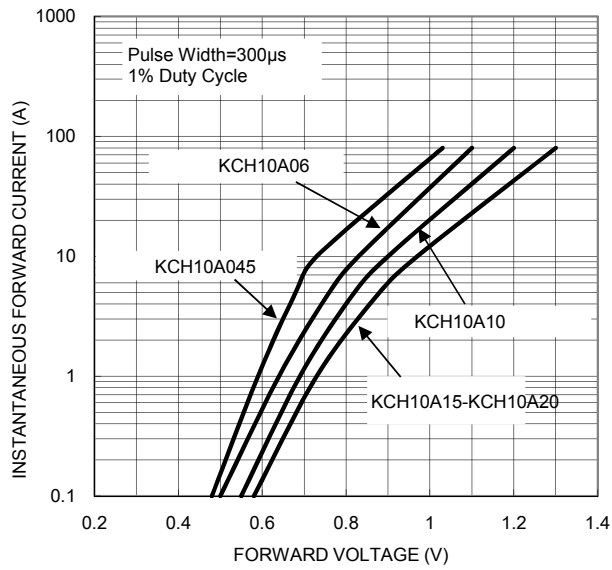


FIG. 4- TYPICAL REVERSE CHARACTERISTICS

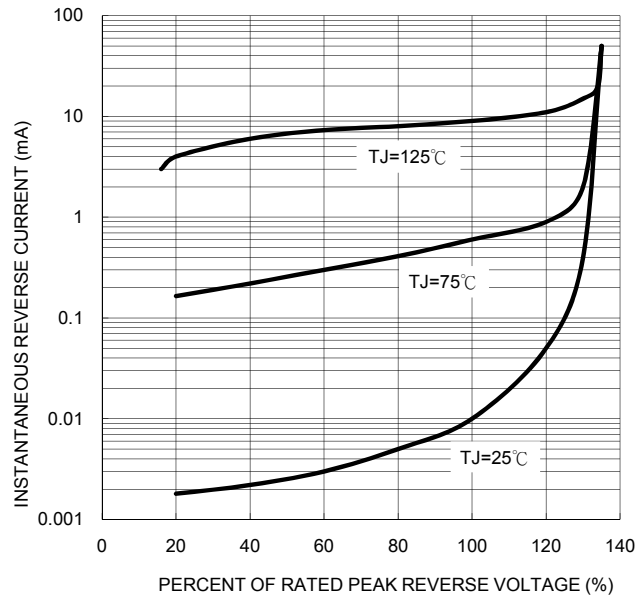


FIG. 5- TYPICAL JUNCTION CAPACITANCE

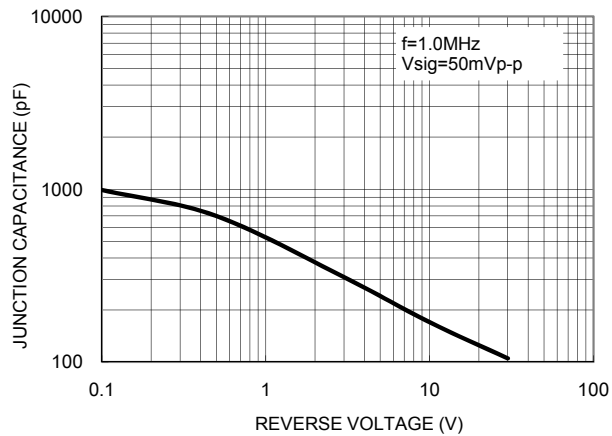


FIG. 6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

